

DESCRIPTION The 2SB1117 is a Low $V_{CE(sat)}$ transistor which has a large current capability and wide ASO. It is suitable for driver of solenoid or motor, or electronic flash.

FEATURES

- Low Collector Saturation Voltage.
 $V_{CE(sat)} = -0.2 \text{ V TYP. (@ } I_C/I_B = -2.0 \text{ A/-0.2 A)}$
- Large Current.
 $I_{C(DC)} = -3.0 \text{ A, } I_{C(pulse)} = -5.0 \text{ A}$
- High DC Current Gain.:
 $h_{FE} = 300 \text{ TYP. (@ } V_{CE} = -2.0 \text{ V, } I_C = -1.0 \text{ A)}$
- High Total Power Dissipation. : $P_T = 1.0 \text{ W}$
- Complementary to the NEC 2SD1617 NPN Transistor.

ABSOLUTE MAXIMUM RATINGS

Maximum Temperatures

Storage Temperature $-55 \text{ to } +150^\circ \text{C}$

Junction Temperature $150^\circ \text{C Maximum}$

Maximum Power Dissipation ($T_a = 25^\circ \text{C}$)

Total Power Dissipation 1.0 W

Maximum Voltages and Currents ($T_a = 25^\circ \text{C}$)

V_{CBO} Collector to Base Voltage -30 V

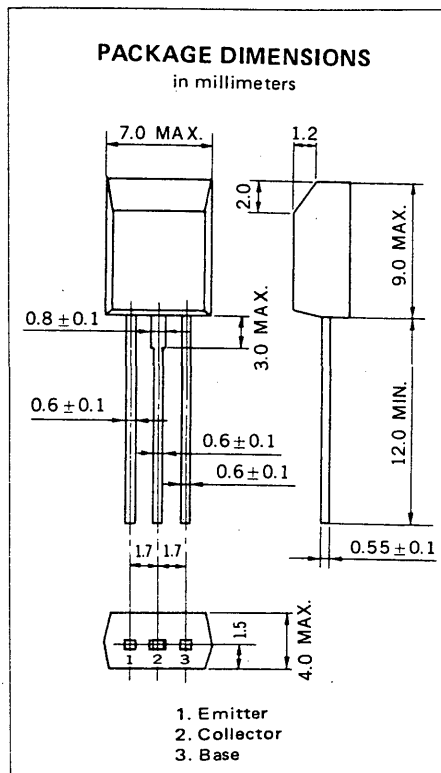
V_{CEO} Collector to Emitter Voltage -25 V

V_{EBO} Emitter to Base Voltage -6.0 V

I_C Collector Current (DC) -3.0 A

I_C Collector Current (pulse)* -5.0 A

*PW $\leq 10 \text{ ms}$, Duty Cycle $\leq 50 \%$



ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ \text{C}$)

SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
h_{FE1}^{**}	DC Current Gain	135	300	600	—	$V_{CE} = -2.0 \text{ V, } I_C = -1.0 \text{ A}$
h_{FE2}^{**}	DC Current Gain	81			—	$V_{CE} = -2.0 \text{ V, } I_C = -2.0 \text{ A}$
f_T	Gain Bandwidth Product	100	280		MHz	$V_{CE} = -5.0 \text{ V, } I_E = 1.0 \text{ A}$
C_{ob}	Output Capacitance		90		pF	$V_{CB} = -10 \text{ V, } I_E = 0, f = 1.0 \text{ MHz}$
I_{CBO}	Collector Cutoff Current			-100	nA	$V_{CB} = -30 \text{ V, } I_E = 0$
I_{EBO}	Emitter Cutoff Current			-100	nA	$V_{EB} = -6.0 \text{ V, } I_C = 0$
V_{BE}^{**}	Base to Emitter Voltage	-600	-660	-700	mV	$V_{CE} = -2.0 \text{ V, } I_C = -0.1 \text{ A}$
$V_{CE(sat)1}^{**}$	Collector Saturation Voltage		-0.2	-0.3	V	$I_C = -2.0 \text{ A, } I_B = -0.2 \text{ A}$
$V_{CE(sat)2}^{**}$	Collector Saturation Voltage		-0.3	-0.5	V	$I_C = -3.0 \text{ A, } I_B = -0.3 \text{ A}$
$V_{BE(sat)}^{**}$	Base Saturation Voltage		-1.0	-1.2	V	$I_C = -2.0 \text{ A, } I_B = -0.2 \text{ A}$
t_{on}	Turn On Time		80		ns	$V_{CE} = -10 \text{ V, } I_C = -500 \text{ mA}$ $I_{B1} = -I_{B2} = -50 \text{ mA}$ $V_{BE(off)} = 2 \text{ to } 3 \text{ V}$
t_{stg}	Storage Time		500		ns	
t_f	Fall Time		70		ns	

**Pulsed PW $\leq 350 \mu\text{s}$, Duty Cycle $\leq 2\%$

Classification of h_{FE1}

Rank	L	K	U
Range	135 to 270	200 to 400	300 to 600

Test Conditions: $V_{CE} = -2.0 \text{ V, } I_C = -1.0 \text{ A}$

TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)